## 2SC1623 TRANSISTOR (NPN)

#### **FEATURE**

High DC current gain : $h_{FE}=200(Typ)V_{CE}=6V$ ,  $I_{C}=1mA$ 

High voltage: V<sub>CEO</sub>=50V

SOT-23

1. BASE
2. EMITTER
3. COLLECTOR

MARKING: L6

### **MAXIMUM RATINGS (**T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Value	Units	
V <sub>CBO</sub>	Collector-Base Voltage	60	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	50	50 V	
V <sub>EBO</sub>	Emitter-Base Voltage	5	V	
Ic	Collector Current -Continuous	100	mA	
Pc	Collector Power Dissipation	200	mW	
TJ	Junction Temperature	150	°C	
T <sub>stg</sub>	Storage Temperature	-55-150	°C	

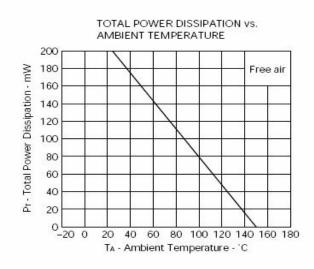
**ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)** 

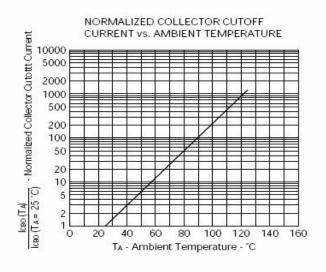
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Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT		
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	   I <sub>C</sub> =100μΑ, I <sub>E</sub> =0	60			V		
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =1mA, I <sub>B</sub> =0	50			V		
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =100μA, I <sub>C</sub> =0	5			V		
Collector cut-off current	I <sub>CBO</sub>	$V_{CB}=60$ V, $I_{E}=0$			0.1	μA		
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB}=5V$ , $I_{C}=0$			0.1	μA		
DC current gain	h <sub>EE</sub>	V <sub>CE</sub> =6V, I <sub>C</sub> =1mA	200		400			
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =100mA, I <sub>B</sub> =10mA			0.3	V		
Base-emitter saturation voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =100mA, I <sub>B</sub> =10mA			1	V		
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =6V, I <sub>C</sub> =10mA		250		MHz		

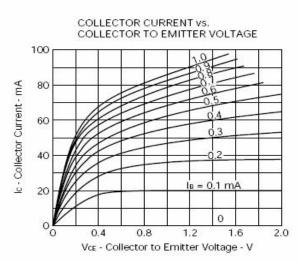
Page 1 of 3 5/30/2011

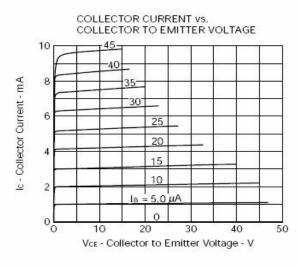
# **Typical Characteristics**

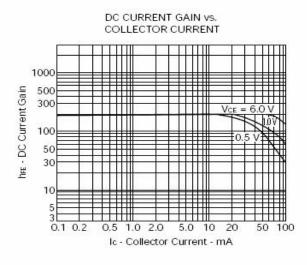
### 2SC1623

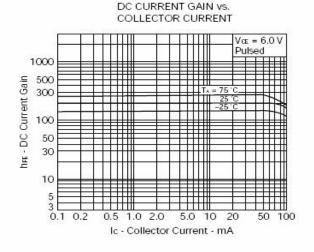










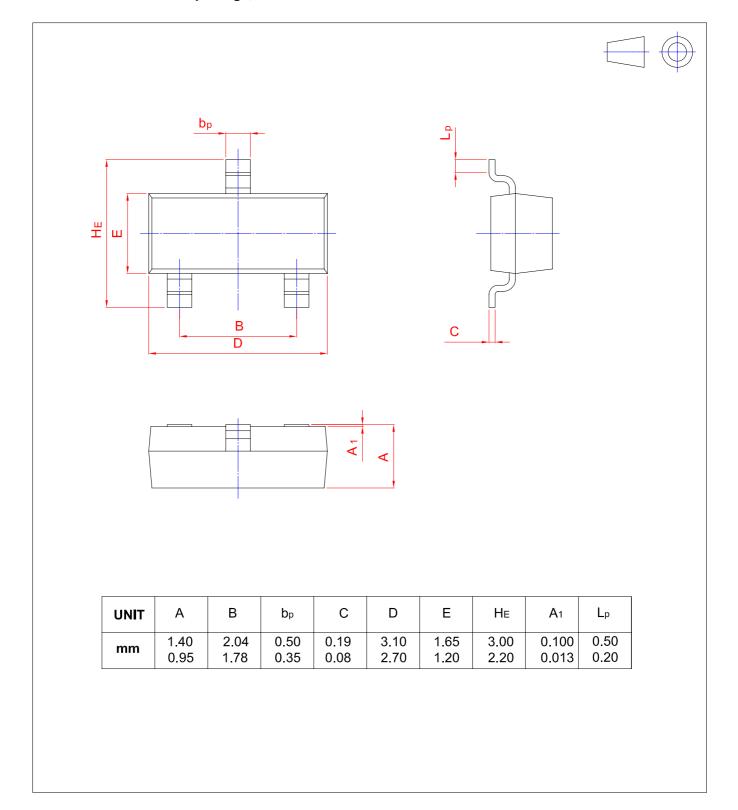


Page 2 of 3 5/30/2011

### **PACKAGE OUTLINE**

#### Plastic surface mounted package; 3 leads

SOT-23



Page 3 of 3 5/30/2011

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